

Product Summary

| $V_{(BR)DSS}$ | $R_{DS(ON)}$ | I_D $T_A = +25^\circ\text{C}$ |
|---------------|-----------------------------|------------------------------------|
| 50V | $2\Omega @ V_{GS} = 5V$ | 300 mA |
| | $2.5\Omega @ V_{GS} = 2.5V$ | 200 mA |

Features and Benefits

- N-Channel MOSFET
- Low On-Resistance
- Very Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- ESD Protected
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

Description and Applications

This MOSFET has been designed to minimize the on-state resistance ($R_{DS(ON)}$) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish annealed over Alloy 42 leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208 (e3)
- Terminal Connections: See Diagram
- Weight: 0.008 grams (approximate)

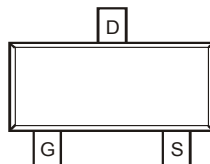


ESD protected

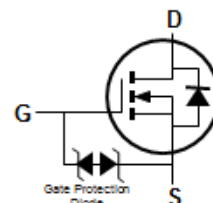


Top View

SOT23



Top View



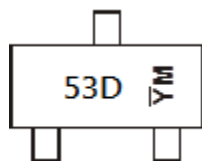
Equivalent Circuit

Ordering Information (Note 4)

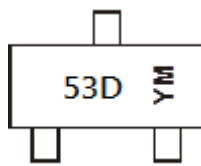
| Part Number | Case | Packaging |
|-------------|-------|-------------------|
| DMN53D0U-7 | SOT23 | 3000/Tape & Reel |
| DMN53D0U-13 | SOT23 | 10000/Tape & Reel |

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

Marking Information



Chengdu A/T Site



Shanghai A/T Site

53D = Product Type Marking Code
 YM = Date Code Marking for SAT (Shanghai Assembly/ Test site)
 Y or Y̅ = Date Code Marking for CAT (Chengdu Assembly/ Test site)
 Y or Y̅ = Year (ex: B = 2014)
 M = Month (ex: 9 = September)

Date Code Key

| Year | 2014 | 2015 | 2016 | 2017 | 2018 | 2019 | 2020 |
|------|------|------|------|------|------|------|------|
| Code | B | C | D | E | F | G | H |

| Month | Jan | Feb | Mar | Apr | May | Jun | Jul | Aug | Sep | Oct | Nov | Dec |
|-------|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|
| Code | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | O | N | D |

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | | Symbol | Value | Unit |
|------------------------|------------|------------------|-------|------|
| Drain Source Voltage | | V _{DSS} | 50 | V |
| Gate-Source Voltage | Continuous | V _{GSS} | ±12 | V |
| Drain Current (Note 5) | Continuous | I _D | 300 | mA |
| | Pulsed | I _{DM} | 500 | |

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | | Symbol | Value | Unit |
|--|--|-----------------------------------|-------------|------|
| Total Power Dissipation (Note 5) | | P _D | 520 | mW |
| Thermal Resistance, Junction to Ambient (Note 5) | | R _{θJA} | 246 | °C/W |
| Operating and Storage Temperature Range | | T _J , T _{STG} | -55 to +150 | °C |

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Typ | Max | Unit | Test Condition |
|---|---------------------|-----|------|-----|------|---|
| OFF CHARACTERISTICS (Note 6) | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | 50 | — | — | V | V _{GS} = 0V, I _D = 250μA |
| Zero Gate Voltage Drain Current | I _{DSS} | — | — | 1 | μA | V _{DS} = 50V, V _{GS} = 0V |
| Gate-Body Leakage | I _{GSS} | — | — | ±10 | μA | V _{GS} = ±12V, V _{DS} = 0V |
| ON CHARACTERISTICS (Note 6) | | | | | | |
| Gate Threshold Voltage | V _{GS(th)} | 0.4 | — | 1.0 | V | V _{DS} = V _{GS} , I _D = 250μA |
| Static Drain-Source On-Resistance | R _{DS(on)} | — | — | 2.0 | Ω | V _{GS} = 5.0V, I _D = 50mA |
| | | — | — | 2.5 | | V _{GS} = 2.5V, I _D = 50mA |
| | | — | — | 3.0 | | V _{GS} = 1.8V, I _D = 50mA |
| Source-Drain Diode Forward Voltage | V _{SD} | — | — | 1.4 | V | V _{GS} = 0V, I _S = 115mA |
| DYNAMIC CHARACTERISTICS (Note 7) | | | | | | |
| Input Capacitance | C _{iss} | — | 37.1 | — | pF | V _{DS} = 25V, V _{GS} = 0V f = 1.0MHz |
| Output Capacitance | C _{oss} | — | 8.4 | — | pF | |
| Reverse Transfer Capacitance | C _{rss} | — | 4.0 | — | pF | |
| Total Gate Charge | Q _g | — | 0.6 | — | nC | V _{GS} = 4.5V, V _{DS} = 10V, I _D = 250mA |
| Gate-Source Charge | Q _{gs} | — | 0.1 | — | nC | |
| Gate-Drain Charge | Q _{gd} | — | 0.1 | — | nC | |
| Turn-On Delay Time | t _{D(on)} | — | 2.1 | — | ns | V _{DD} = 30V, V _{GS} = 10V, R _G = 25Ω, I _D = 200mA |
| Turn-On Rise Time | t _r | — | 2.8 | — | ns | |
| Turn-Off Delay Time | t _{D(off)} | — | 21 | — | ns | |
| Turn-Off Fall Time | t _f | — | 14 | — | ns | |

- Notes:
- Device mounted on FR-4 substrate PC board, 2oz copper, with thermal vias to bottom layer 1inch square copper plate
 - Short duration pulse test used to minimize self-heating effect.
 - Guaranteed by design. Not subject to product testing.

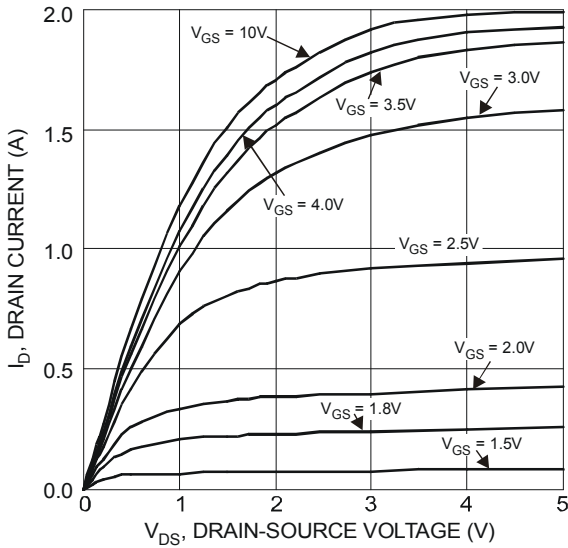


Figure 1 Typical Output Characteristics

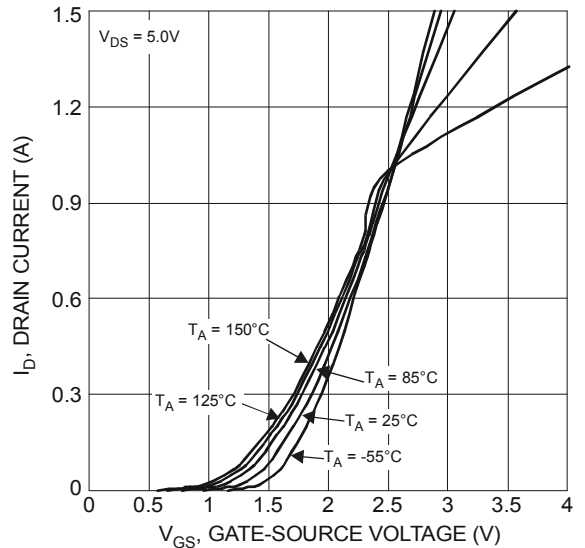


Figure 2 Typical Transfer Characteristics

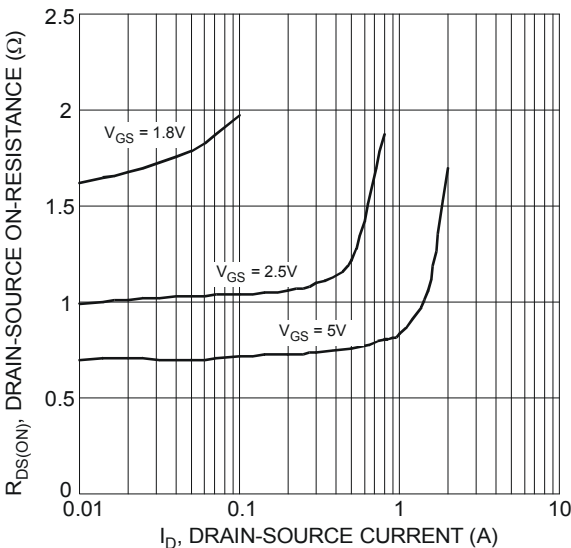


Figure 3 Typical On-Resistance vs. Drain Current and Gate Voltage

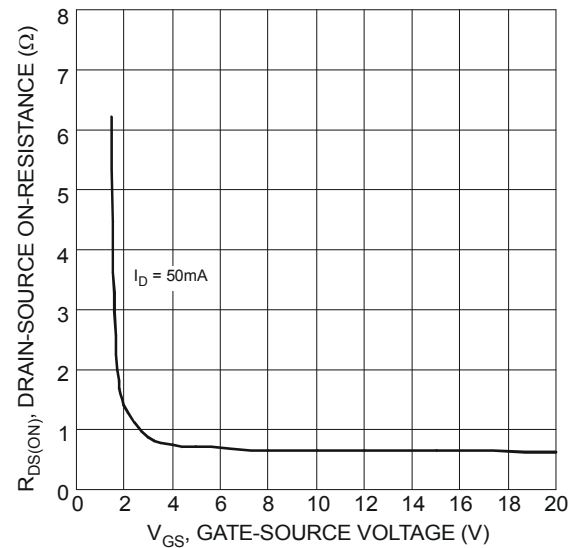


Figure 4 Typical Transfer Characteristics

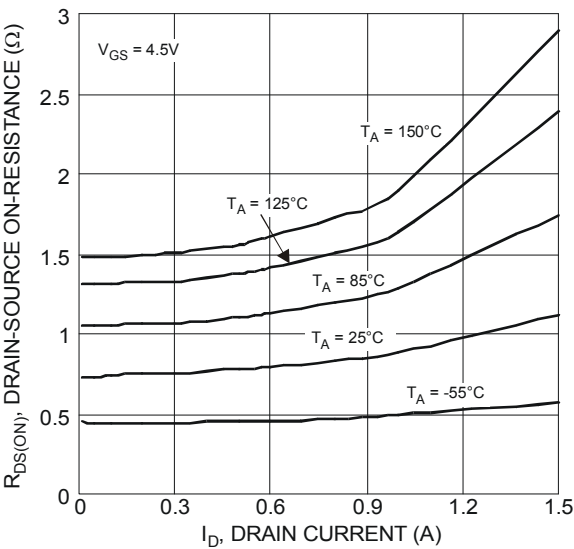


Figure 5 Typical On-Resistance vs. Drain Current and Temperature

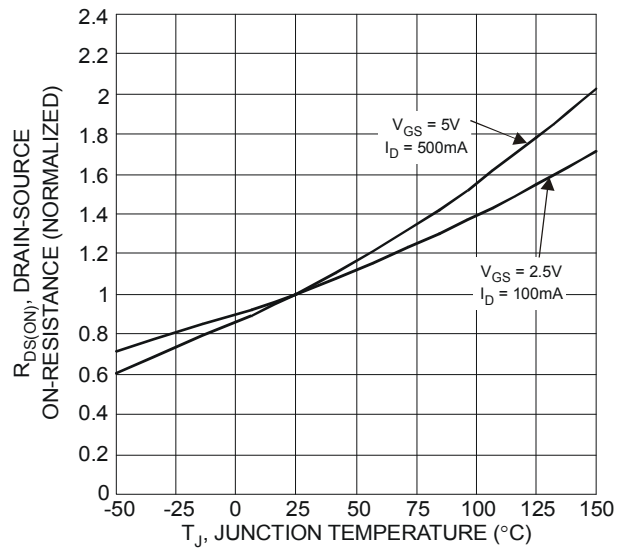


Figure 6 On-Resistance Variation with Temperature

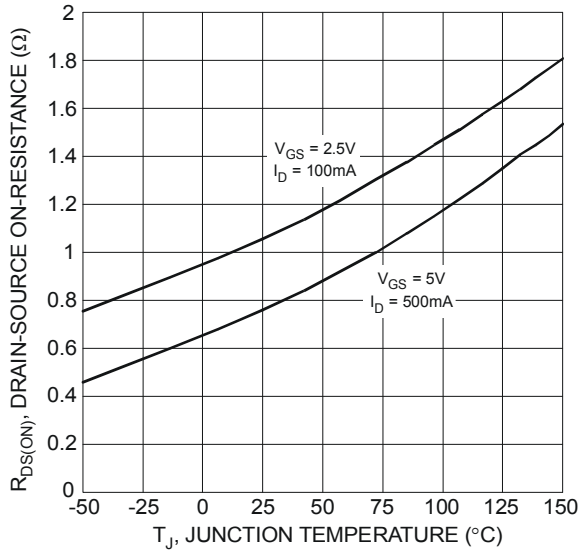


Figure 7 On-Resistance Variation with Temperature

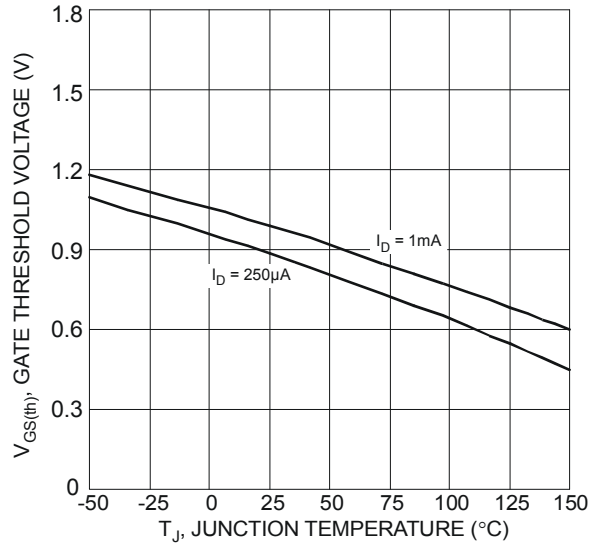


Figure 8 Gate Threshold Variation vs. Ambient Temperature

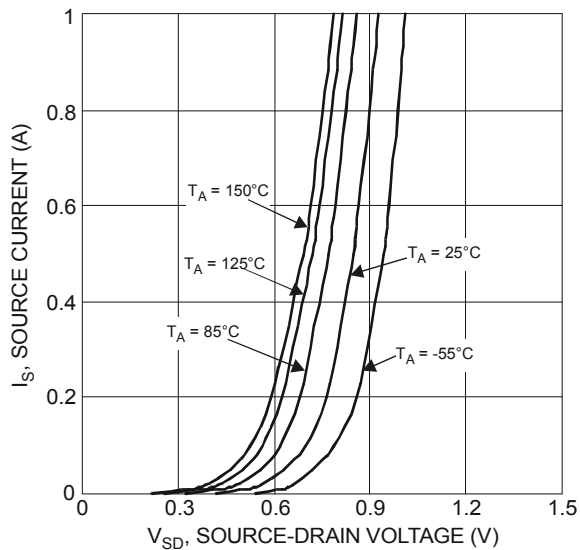


Figure 9 Diode Forward Voltage vs. Current

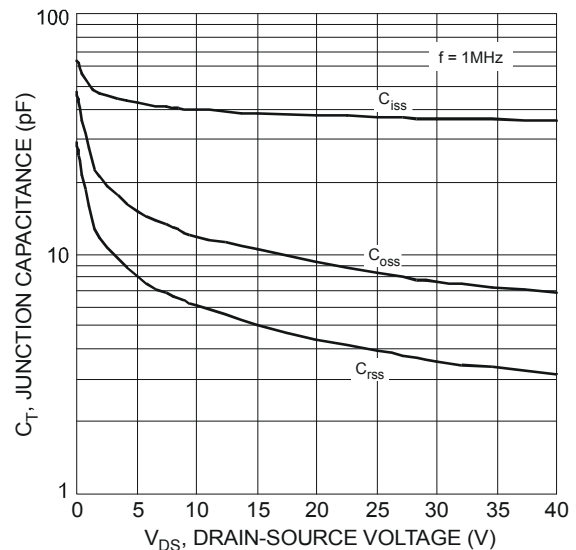


Figure 10 Typical Junction Capacitance

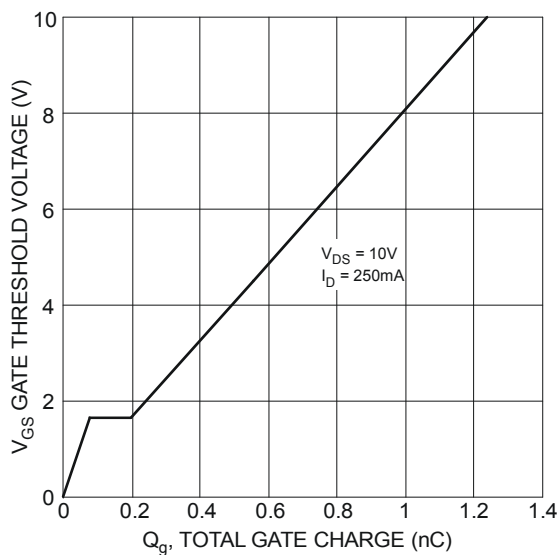
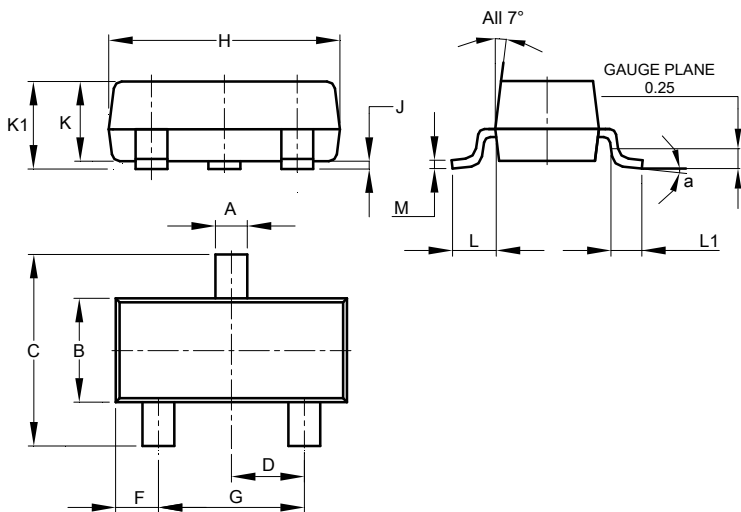


Figure 11 Gate Charge

Package Outline Dimensions

Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.

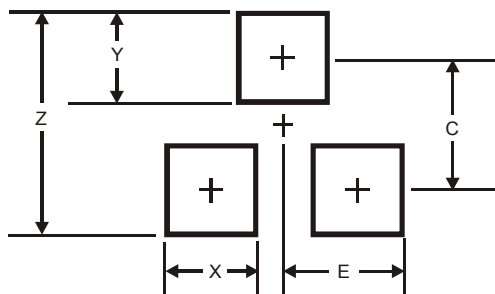


| SOT23 | | | |
|----------------------|-------|-------|-------|
| Dim | Min | Max | Typ |
| A | 0.37 | 0.51 | 0.40 |
| B | 1.20 | 1.40 | 1.30 |
| C | 2.30 | 2.50 | 2.40 |
| D | 0.89 | 1.03 | 0.915 |
| F | 0.45 | 0.60 | 0.535 |
| G | 1.78 | 2.05 | 1.83 |
| H | 2.80 | 3.00 | 2.90 |
| J | 0.013 | 0.10 | 0.05 |
| K | 0.890 | 1.00 | 0.975 |
| K1 | 0.903 | 1.10 | 1.025 |
| L | 0.45 | 0.61 | 0.55 |
| L1 | 0.25 | 0.55 | 0.40 |
| M | 0.085 | 0.150 | 0.110 |
| α | 8° | | |
| All Dimensions in mm | | | |

NEW PRODUCT

Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



| Dimensions | Value (in mm) |
|------------|---------------|
| Z | 2.9 |
| X | 0.8 |
| Y | 0.9 |
| C | 2.0 |
| E | 1.35 |

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